MIC94050/94051

4-Terminal TinyFET™ P-Channel MOSFET

Final

General Description

The MIC94050 and MIC94051 are 4-terminal silicon gate P-channel MOSFETs that provide low on-resistance in a very small package.

Designed for high-side switch applications where space is critical, the MIC94050/1 exhibits an on-resistance of typically 0.125Ω at 4.5V gate-to-source voltage. The MIC94050/1 also operates with only 1.8V gate-to-source voltage.

The MIC94050 is the basic 4-lead P-channel MOSFET. The MIC94051 is a variation that includes an internal gate pull-up resistor that can reduce the system parts count in many applications.

The 4-terminal SOT-143 package permits a substrate connection separate from the source connection. This 4-terminal configuration improves the θ_{JA} (improved heat dissipation) and makes reverse-blocking switch applications practical.

The small size, low threshold, and low $R_{DS(on)}$ make the MIC94050/1 the ideal choice for PCMCIA, USB, back-up battery-power, and distributed power management applications.

Features

- 0.125Ω typical on-resistance at 4.5V gate-to-source voltage
- Operates with 1.8V gate-to-source voltage
- Separate substrate connection allows reverse-blocking

Applications

- Distributed power management
- PCMCIA card power management
- USB ports
- Battery-powered computers, peripherals
- Handheld bar-code scanners
- Portable communications equipment
- Reverse blocking battery management

Ordering Information

Part Number	Temperature Range*	Package
MIC94050BM4	−40°C to +150°C	SOT-143
MIC94051BM4	−40°C to +150°C	SOT-143

* Operating Junction Temperature

Pin Configuration

Part Number	Identification
MIC94050BM4	P50
MIC94051BM4	P51

SOT-143 Package (M4)
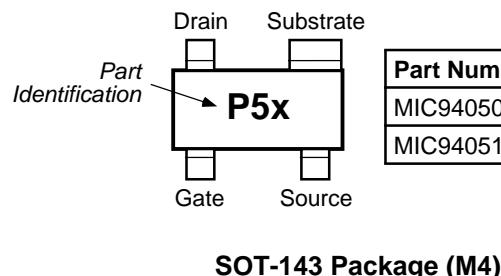
Typical PCB Layout
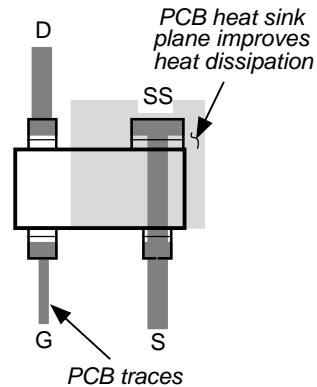
Schematic Symbol
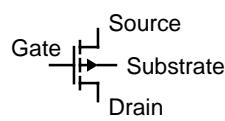
Schematic Symbol

Functional Diagrams
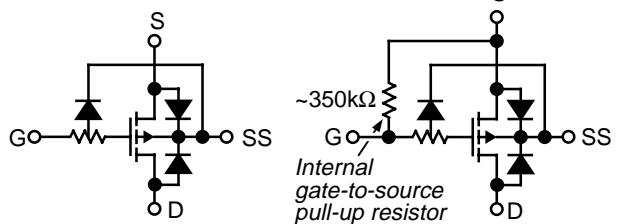
MIC94050   **MIC94051**

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Absolute Maximum Ratings

Drain-to-Source Voltage .... –6V

Gate-to-Source Voltage .... –6V

Continuous Drain Current

T_A = 25°C (V_{GS} = 4.5V) 1.8A

T_A = 100°C (V_{GS} = 4.5V) 1.2A

Total Power Dissipation

T_A = 25°C 568mW

T_A = 100°C 227mW

Operating Junction Temperature .... –40°C to +150°C

Storage Temperature .... –55°C to +150°C

ESD Rating, **Note 2**

Operating Ratings

Thermal Resistance

θ_{JA} .... 220°C/W

θ_{JC} .... 130°C/W

Electrical Characteristics (Note 1)

Symbol	Parameter	Condition (Note 1)	Min	Typ	Max	Units
V_{GS}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	0.5		1.2	V
I_{GSS}	Gate-Body Leakage	V_{DS} = 0V, V_{GS} = –4.5V, **Note 2**, **Note 3**			1	μA
R_{GS}	Gate-Source Resistance	V_{DS} = 0V, V_{GS} = –4.5V, **Note 2**, **Note 4**	200	350	500	kΩ
C_{ISS}	Input Capacitance	V_{GS} = 0V, V_{DS} = –5.5V		600		pF
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = –5.5V, V_{GS} = 0V			1	μA
		V_{DS} = –5.5V, V_{GS} = 0V, T_J = 85°C			5	μA
$R_{DS(ON)}$	Drain-Source On-Resistance	V_{GS} = –4.5V, I_D = –100mA		0.125	0.160	Ω
		V_{GS} = –3.6V, I_D = –100mA		0.135	0.180	Ω
		V_{GS} = –2.5V, I_D = –100mA		0.165	0.200	Ω
		V_{GS} = –1.8V, I_D = –100mA		0.225	0.280	Ω
g_{FS}	Forward Transconductance	V_{DS} = –5.5V, I_D = –200mA, **Note 5**		3		S

Note 1. T_A = 25°C unless noted. Substrate connected to source for all conditions.

**Note 2.** ESD gate protection diode conducts during positive gate-to-source voltage excursions. IC devices are inherently ESD sensitive. Handling precautions required

Note 3. MIC94050 only.

Note 4. MIC94051 only.

Note 5. Pulse Test: Pulse Width ≤ 80μs, Duty Cycle ≤ 0.5%.

Typical Characteristics

Drain Characteristics

**On-Resistance vs.
Gate-to-Source Voltage**

**$R_{DS(ON)}$
vs. Drain Current**

**Source Drain Diode
Forward Voltage Drop
vs. Current**

**Gate Threshold
vs. Temperature**

**$R_{DS(ON)}$ Variance
vs. Temperature**
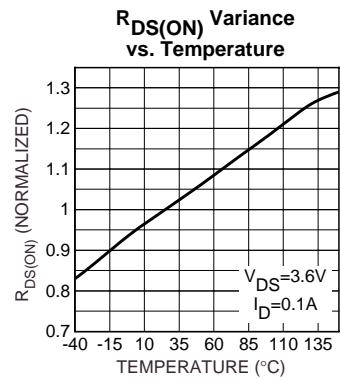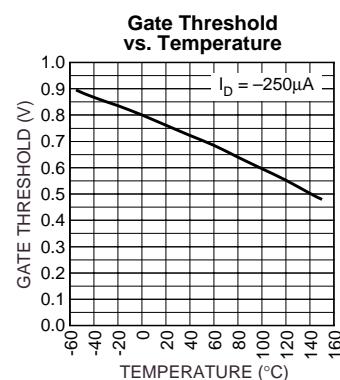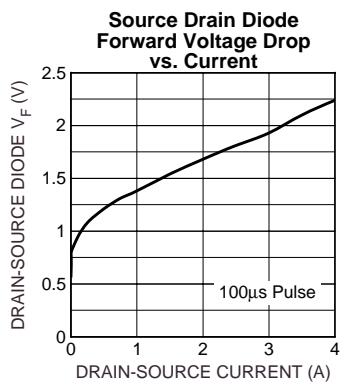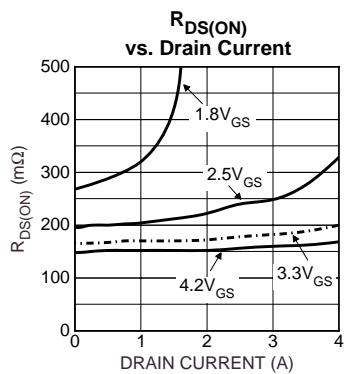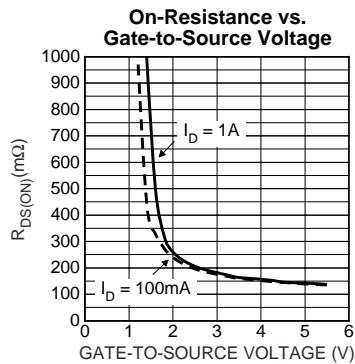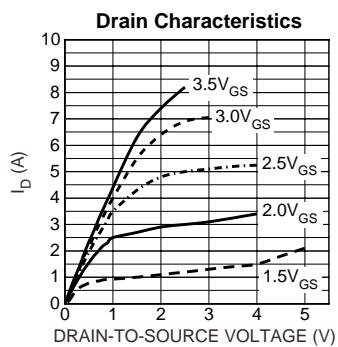
Typical Applications
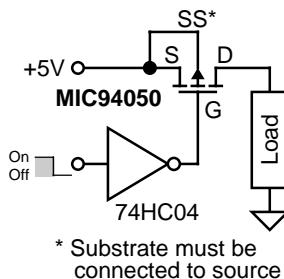
Figure 1. Load Switch Application
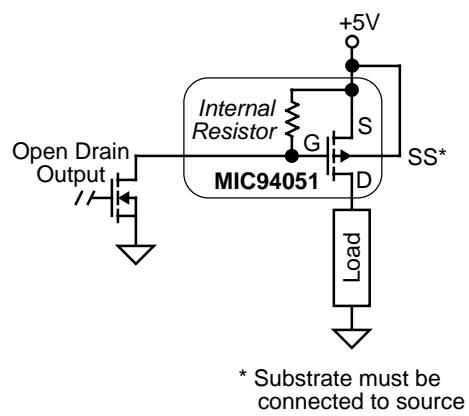
**Figure 2. Load Switch Application
(with internal gate-source pull-up)**

A	B	Output
Off	Off	0V
On	Off	+4V
Off	On	Li Coin Cell
On	On	*don't!*
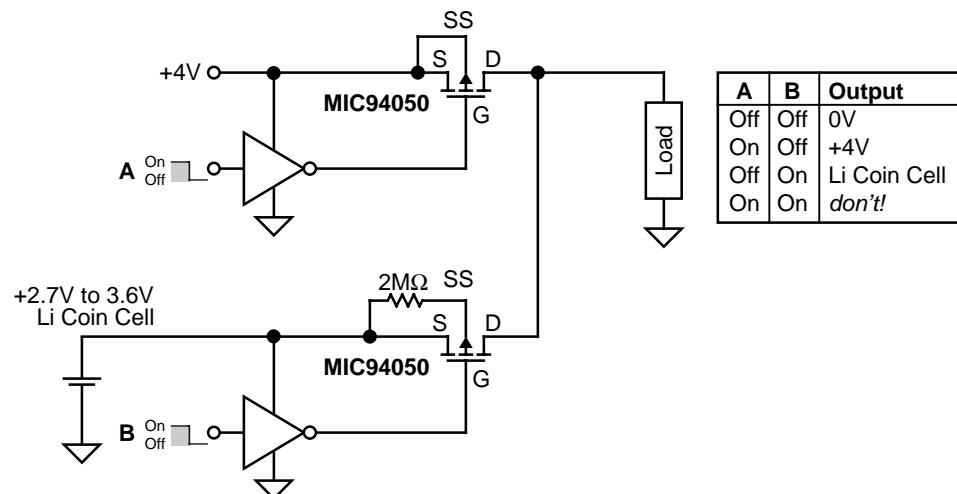
Figure 3. Reverse-Blocking Battery Back-Up Application

Package Information

0.950 (0.0374) TYP

1.40 (0.055)
1.20 (0.047)

2.50 (0.098)
2.10 (0.083)

DIMENSIONS:
MM (INCH)

3.05 (0.120)
2.67 (0.105)

1.12 (0.044)
0.81 (0.032)

8°
0°

0.150 (0.0059)
0.089 (0.0035)

0.800 (0.031) TYP

0.400 (0.016) TYP 3 PLACES

0.10 (0.004)
0.013 (0.0005)

0.41 (0.016)
0.13 (0.005)

SOT-143 (M4)